Bilayer graphene for quantum information science

Christoph Stampfer[1,2]
1 JARA-FIT and 2nd Institute of Physics, RWTH Aachen University, 52074 Aachen, Germany, EU
2 Peter Grünberg Institute (PGI-9), Forschungszentrum Jülich, 52425 Jülich, Germany, EU

stampfer@physik.rwth-aachen.de

Graphene and bilayer graphene (BLG) are attractive platforms for quantum circuits with potential applications in the area quantum information. This has motivated substantial efforts in studying quantum dot devices based on graphene and bilayer graphene. A major challenge in this context is the missing band-gap in graphene, which does not allow to confine electrons by means of electrostatics making ultra-clean displacement field-gapped BLG particularly interesting [1,2].
Here we present gate-controlled single and double quantum dots in electrostatically gaped BLG [3-9]. We show a remarkable degree of control of our devices (Fig. 1), which allow realizing electron-hole and electron-electron double quantum dot systems with single-electron occupation. In both, the single and double quantum dot devices, we reach the very few electron/hole regime, we are able to extract excited state energies and investigate their evolution in a parallel and perpendicular magnetic field. Finally, we will show data on ultra-clean BLG quantum dots allowing investigating the spin-valley coupling in bilayer graphene. Our work paves the way for the implementation of spin and valley-qubits in graphene.

References

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Figures

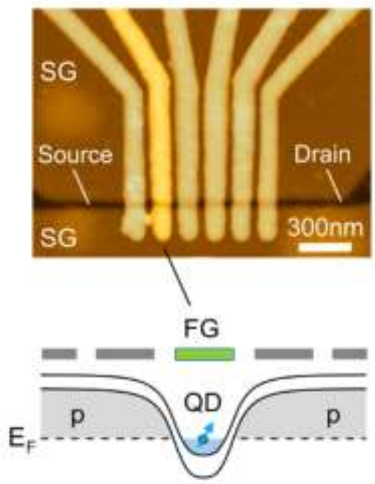

Figure 1: Scanning force microscope image and potential landscape of a BLG quantum dot device.